

CONTROLLED IMPEDANCE

GENERAL PARAMETERS:

Top layer copper foil thickness: 17.5 um
Dielectric thickness from Top to L2 = 173um (6.8 mils)
Dielectric between Top layer and 2nd layer relative permittivity (Er): 4.2

Bottom layer copper foil thickness: 17.5 um
Dielectric thickness from L11 to Bottom = 173um (6.8 mils)
Dielectric between L11 layer and Bottom layer relative permittivity (Er): 4.2
Ground plane distance to trace on Bottom layer: 0.1mm

CALCULATIONS:

50 Ohm microstrip (Top layer, no GND) characteristics:
Top layer copper foil thickness: 17.5 um
Track width = 0.325 mm (12.795 mils)
Dielectric thickness from Top to L2 = 173um (6.8 mils)
Dielectric between Top layer and 2nd layer relative permittivity (Er): 4.2

Approximate microstrip line impedance = 49.99 Ohms (+/- 10% tolerance)

100 Ohm coupled microstrip line (Top layer) characteristics:
Top layer copper foil thickness: 17.5 um
Track width = 0.2 mm (6.8 mils)
Track spacing = 0.14 mm (5.51 mils)
Track width/spacing ratio = 1.428
Dielectric thickness from top to L2 = 173um (6.8 mils)
Dielectric between Top layer and 2nd layer relative permittivity (Er): 4.2

Approximate coupled microstrip line impedance = 100.752 Ohms (+/- 10% tolerance)

50 Ohm coplanar waveguide with GND (Bottom layer) characteristics:
Bottom layer copper foil thickness: 17.5 um
Track width = 0.254 mm (10 mils)
Distance to GND: 0.1 mm (3.937 mils)
Dielectric thickness from Bottom to L11 = 173um (6.8 mils)
Dielectric between Bottom layer and L11 relative permittivity (Er): 4.2

Approximate microstrip line impedance = 49.99 Ohms (+/- 10% tolerance)

90 Ohm coupled microstrip line (Top layer, without GND) characteristics:
Top layer copper foil thickness: 17.5 um
Track width = 0.2 mm (6.8 mils)
Track spacing = 0.1 mm (3.93 mils)
Track width/spacing ratio = 2
Dielectric thickness from Top to 2nd layer = 173um (6.8 mils)
Dielectric between Top layer and 2nd layer relative permittivity (Er): 4.2

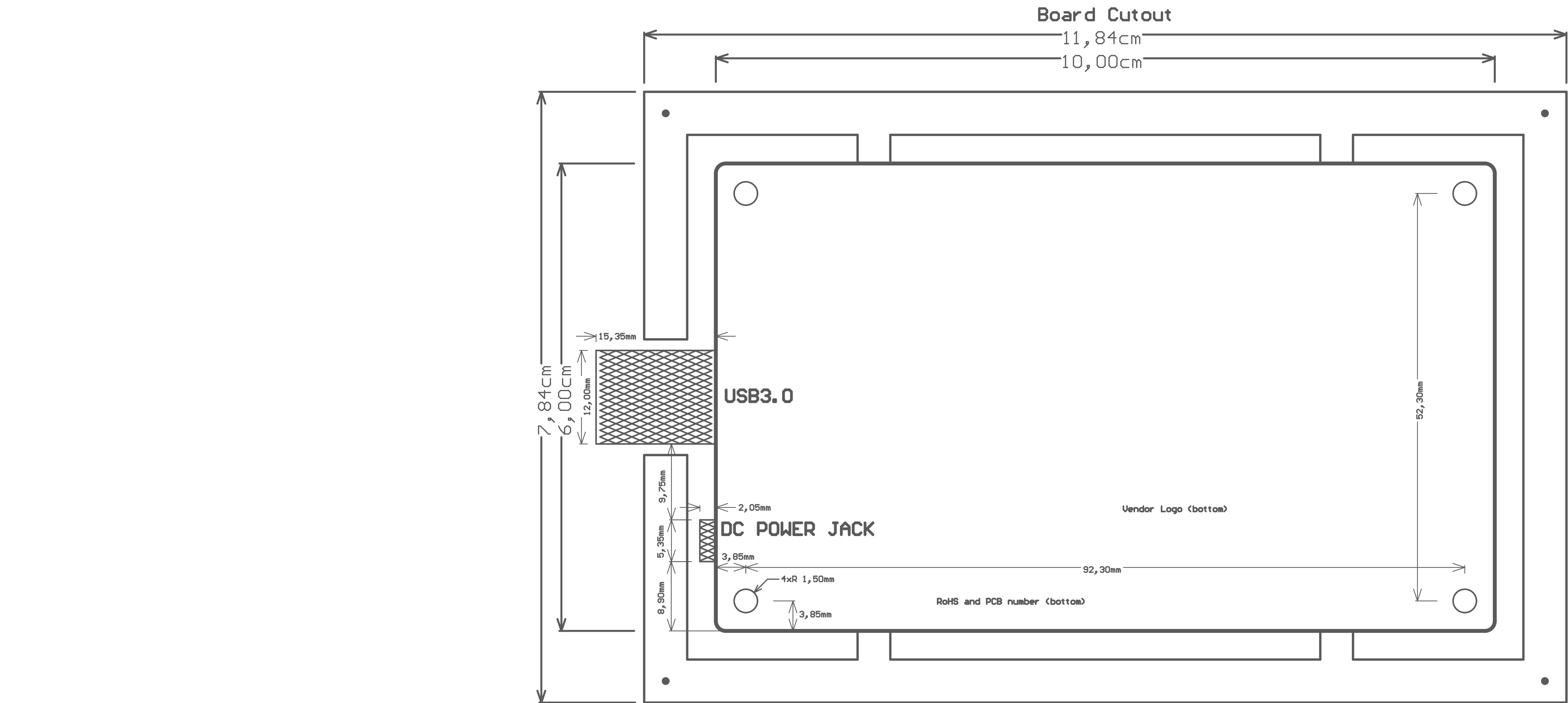
Approximate coupled microstrip line impedance = 90.5 Ohms (+/- 10% tolerance)

90 Ohm coupled microstrip line (Bottom layer) characteristics:
Bottom layer copper foil thickness: 17.5 um
Track width = 0.2 mm (6.8 mils)
Track spacing = 0.1 mm (3.93 mils)
Track width/spacing ratio = 2
Dielectric thickness from L11 to Bottom layer = 173um (6.8 mils)
Dielectric between L11 layer and Bottom layer relative permittivity (Er): 4.2

Approximate coupled microstrip line impedance = 90.5 Ohms (+/- 10% tolerance)

VERY IMPORTANT NOTES:

- 0.35mm ring and 0.2mm drill via-in-pads (IC1) must be resin filled with metal cap
- Solder mask : DARK BLUE, both sides, halogen free, glossy finish (NOT matte)
- Silkscreen : white epoxy ink, halogen free, both sides. No silkscreen on pads.
- DRCs must be run on Gerber files before building boards
- Hole diameters are final manufactured diameters INCLUDING HOLE METALIZATION.
- Minimum track spacing: 0.1 mm
Minimum track width: 0.1 mm
- There are plated and non-plated holes on the PCB
- Material:
IT-180A
PCB vendor to silkscreen UL and RoHS compliance marks, vendor logo and date code on bottom where shown
Copper weight: External layers 0.5 oz+plating
Internal layers 1 oz
- Electrical test : 100 % netlist.
- Boards are to be individually bagged.



GERBER LAYER NAMES:

GTP	Top solder paste
GTO	Silkscreen
GTS	Soldermask (halogen free)
GTL	0.5oz+plating
G1	0.1oz
G2	0.1oz
G3	0.1oz
G4	0.1oz
G5	0.1oz
G6	0.1oz
G7	0.1oz
G8	0.1oz
G9	0.1oz
G10	0.1oz
GBL	0.5oz+plating
GBS	Soldermask (halogen free)
GBD	Silkscreen
GBP	Bottom solder paste

STACKUP:

TH via
Top-Bot

ELECTRICAL LAYERS:

Top: RF/GND
L2: GND
L3: PWR/Signal/GND
L4: Signal/PWR/GND
L5: PWR/GND
L6: Signal/GND
L7: GND
L8: Signal
L9: Signal
L10: CLK/Signal
L11: GND
Bottom: Signal/PWR/GND

ADDITIONAL LAYERS:

Mechanical 1: Board cutout
ASM TOP: Assembly top
ASM BOT: Assembly bottom
Mechanical 13: Component 3D body

Total PCB thicknes: 1.6mm +/- 10%

Via type #1
0.2mm drill
0.4mm ring

Via type #2 (In pad, resin filled with metal cap)
0.2mm drill
0.35mm ring